

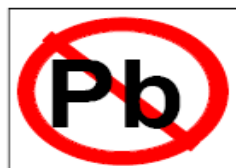


Spec. No.	PS-DS-2D100V
Rev.	A

PRODUCT SPECIFICATION

Model No.: CSDS-2D100V

Descriptions:
<ul style="list-style-type: none"> ■ 2.3 Inch Single Digit Display ■ Common Anode ■ Emitting Color: Super Bright Orange ■ Black Face ■ White Segment



CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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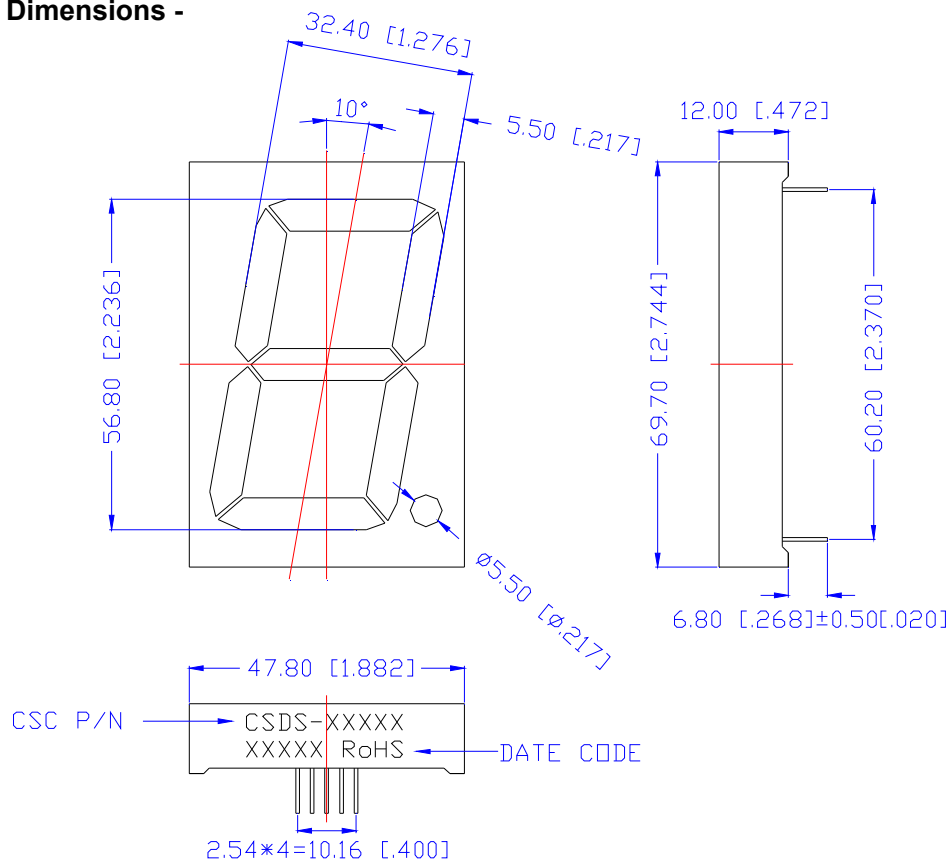
Features -

1. 2.3 inch (56.80mm) digit height.
2. Case mold type.
3. RoHS compliant.
4. Low power consumption.
5. Standard: black face, white segment.
6. Easy mounting on P.C. board or socket.

Device Selection Guide -

Model No.	Chip		Description
	Material	Emitting Color	
CSDS-2D100V	AlGaInP	Super Bright Orange	Common Anode

Mechanical Dimensions -



Notes:

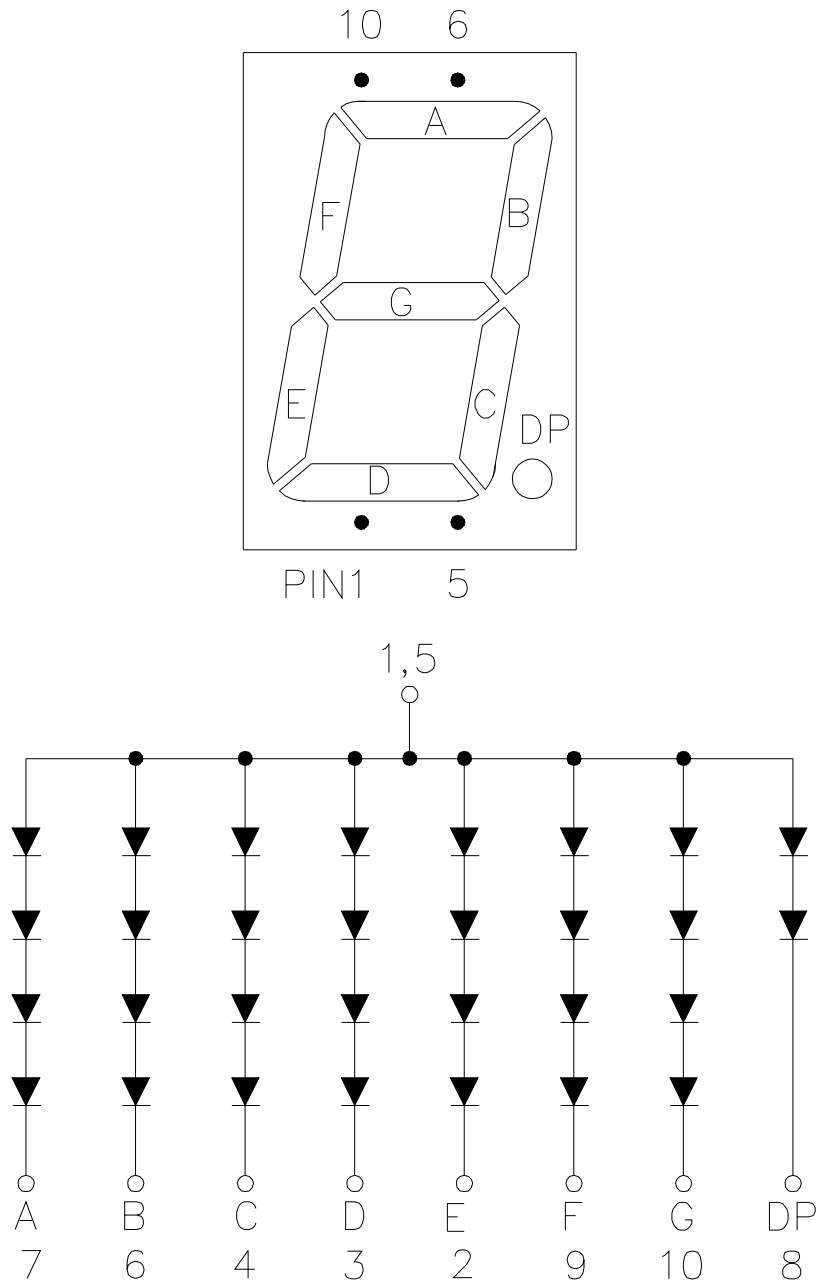
1. All pins are $\phi 0.60$ [0.024]
2. Dimension in millimeter [inch], tolerance is ± 0.25 [0.010] and angle is $\pm 1^\circ$ unless otherwise noted.
3. Bending \leq Length * 1%.



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■ Internal Circuit Diagrams -





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■ Absolute Maximum Rating -

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	P _{AD}	70	mW
Derating Liner from 25°C per Dice	-	0.33	mA/°C
Continuous Forward Current Per Dice	I _{AF}	25	mA
Peak Current Per Dice(duty cycle 1/10,1KHz)	I _{PF}	90	mA
Reverse Voltage Per Dice	VR	5	V
Operating Temp.	T _{opr}	-35 ~ +85	°C
Storage Temp.	T _{stg}	-35 ~ +85	°C

■ Electro-optical Characteristics -

(Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment(DP)	V _F	-	8.0(4.0)	11.2(5.6)	V	I _F =20mA
Luminous Intensity Per Segment	I _v	76	200	-	mcd	I _F =10mA
Peak Emission Wavelength	λ _P	-	632	-	nm	I _F =20mA
Dominant Wavelength	λ _d	-	624	-	nm	I _F =20mA
Spectrum Radiation Bandwidth	Δλ	-	20	-	nm	I _F =20mA
Reverse Current(DP)	I _R	-	-	100	μA	VR=20V(10V)
Luminous Intensity Matching Ratio	I _{V-m}	-	-	2:1	-	I _F =10mA



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■ Typical Electrical / Optical Characteristics Curves -

(Ta = 25°C Unless Otherwise Noted)

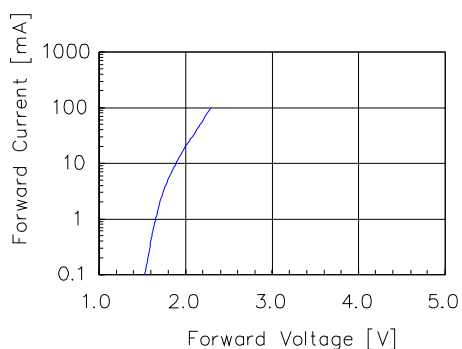


Fig 1. Forward Current vs. Forward Voltage

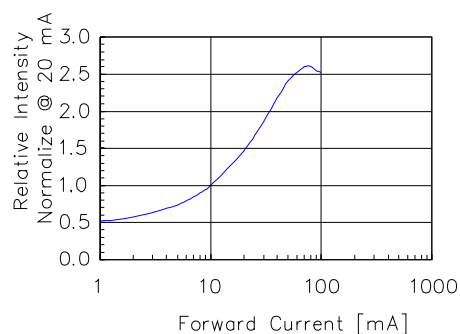


Fig 2. Relative Intensity vs. Forward Current

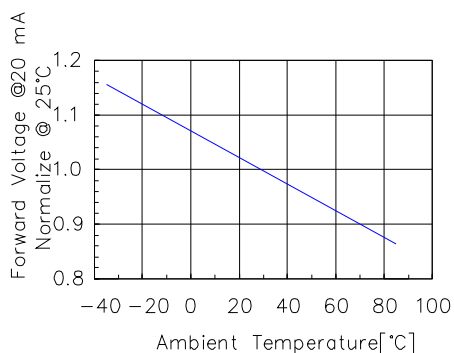


Fig 3. Forward Voltage vs. Temperature

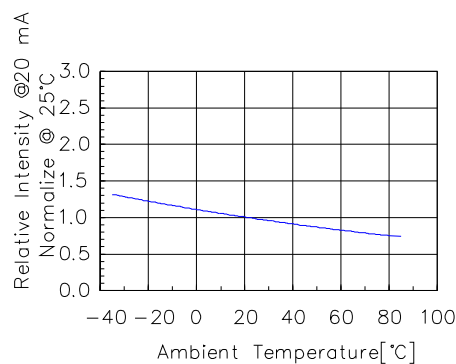


Fig 4. Relative Intensity vs. Temperature

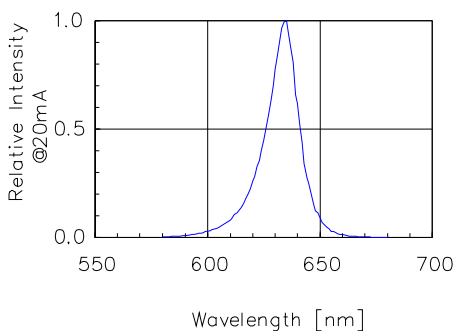


Fig 5. Relative Intensity vs. Wavelength

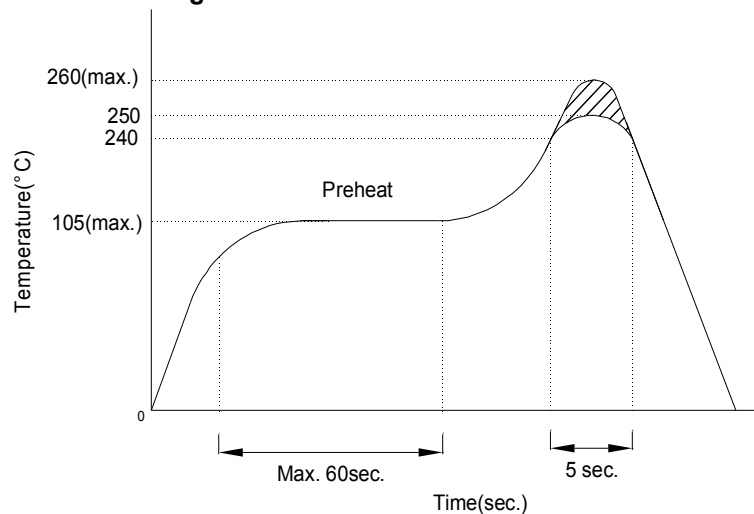


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■ Precautions For Use -

1. Recommended Soldering conditions

Wave Soldering



2. Soldering Iron

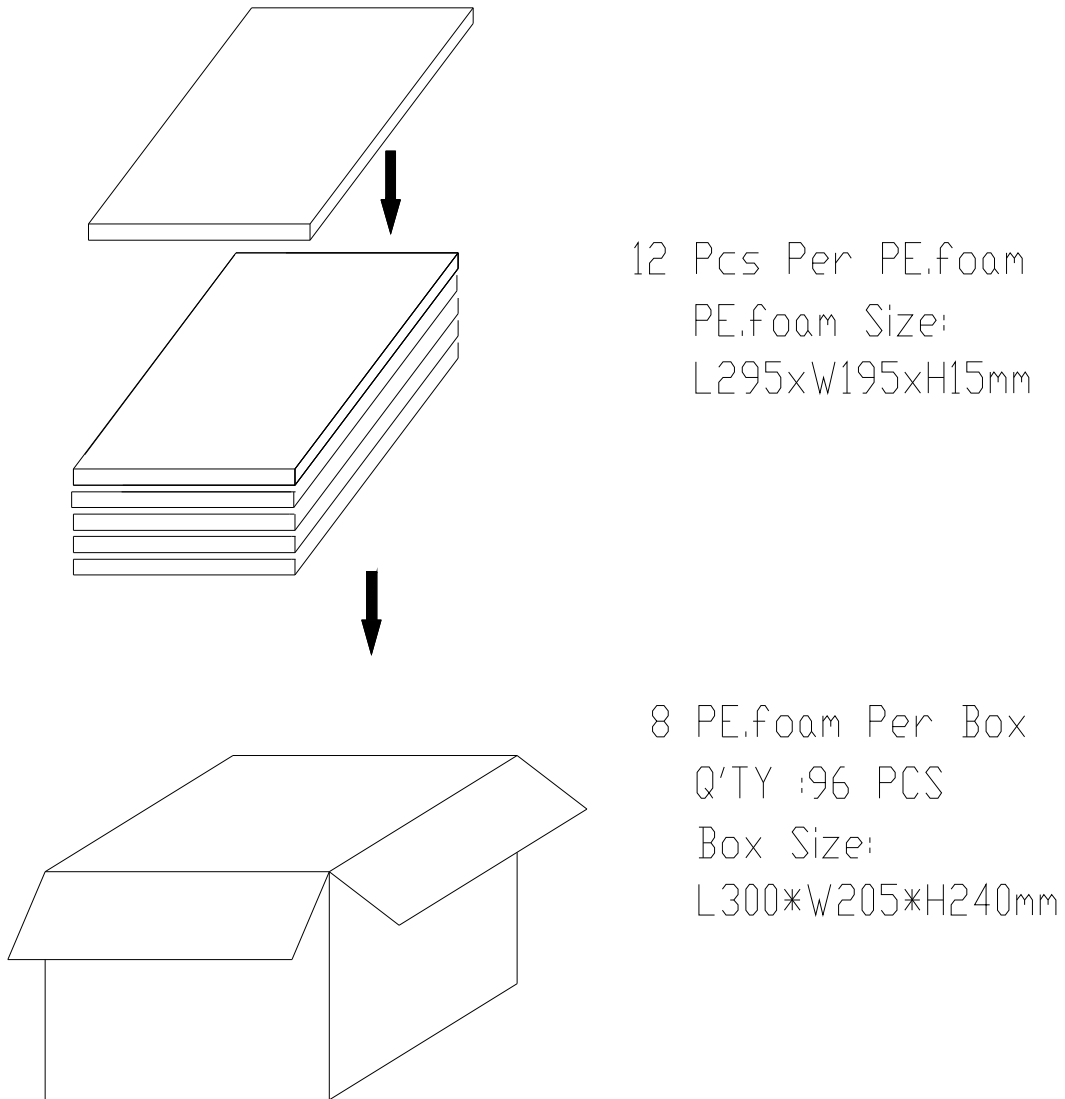
Basic SPEC. is ≤ 5 sec. When 260°C . If temperature is higher, time should be shorter ($+10^{\circ}\text{C} \rightarrow -1$ sec.). Power dissipation of iron should be smaller than 15W, and temperature should be controllable. Surface temperature of the device should be under 230°C .



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■ Package Dimensions



Note: The specifications are subject to change without notice. Please contact us for updated information.